

Stochastic resonance induced by random fields in ferroelectrics

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Abstract

We propose a mechanism of stochastic resonance induced by spatial noise (electric random fields) in ferroelectrics. The calculations demonstrate the characteristic of the stochastic resonance: certain random field can increase the susceptibility, the phonon occupancy, and the overcooled temperature. This mechanics of stochastic resonance may be general in other disordered systems.

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Stochastic resonance (SR) is a nonlinear phenomenon in which the degree of order rather than disorder can be enhanced by the presence of optimized random noise.¹ It was originally proposed to explain the periodicity in the recurrences of the Earth's ice ages as the result of stochastic and weak periodic forces acting in concert on a bistable global climate model.² Experimentally, SR was first demonstrated in a Schmitt trigger circuit and a bistable ring-laser system.³ Since then stochastic resonance has been reported in various systems from crayfish to SQUID and spin system.^{4,5} Variations and extensions of the classical definition of SR were also developed to include aperiodic (e.g., dc or wideband) signals. SR is particularly interesting for neurobiological systems because it provides a mechanism for such systems to detect and process weak signals.^{4,6} In applications, SR may be useful in physical, technological and biomedical contexts.

Stochastic resonance usually occurs in systems with multiple stable states. On the other hand, ferroelectrics are known as multistable systems since the polarization can emerge along more than one directions. In the so called relaxor ferroelectrics (relaxors) such as $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ (PMN), there exists spatial random electric fields induced by point charge defects, nano-domain textures, and the direct interactions of polar ions, etc.⁷ Some specific characteristics of the relaxors were interpreted in terms of different models adopting random fields.⁸ Recently, it was shown that an optimal intensity of random fields can promote the spontaneous appearance of a first-order phase transition by increasing the overcooled temperature of ferroelectrics.⁹ Well then a question naturally arises: *Can the random fields in ferroelectrics produce a certain stochastic resonance?*

To resolve the above problem, in this paper we investigate a ferroelectric system with random fields, and show that a stochastic resonance does occur in this case.

The basic picture of stochastic resonance is generally illustrated using the following simple example:^{1,10} Imagine a particle subject to friction, moving in a double-well potential. A weak periodic signal force is applied on the particle (here, “weak” means that the signal force is far too small to excite the particle over the barrier between the wells). Meanwhile, random noise is applied to tilt the potential and could result in irregular switching of the particle between

the wells. With the help of certain noise, the weak periodic signal can effectively make the particle hop over the barrier, and produce the maximal signal-to-noise ratio (SNR) at a nonzero level of input noise. This phenomenon is called stochastic resonance. In general, it is assumed that the signal period is longer than some characteristic intrawell relaxation time for the system. According to the statistical mechanics, the time average of a mechanical quantity of a system is equal to the ensemble average (ergodic hypothesis). So the above stochastic resonance can be constructed in another way: many particles moving in different double-well potentials, respectively. In this case, the applied noise does not change in time, but changes in space, i.e., double-well potentials tilt in random slopes. This is just the physical picture of the ferroelectric system with random fields where the tilt of potential is caused by random electric fields.¹¹ Therefore, a stochastic resonance with “spatially extended” noise can be reasonably expected in ferroelectrics.

For the ferroelectrics with the second-order phase transition, it was shown that the critical temperature monotonously declines with increasing random fields.¹¹ In this case, even if a phenomenon of stochastic resonance appears, it seems not to lead to interesting practical applications. Therefore, in this paper, we focus our study on the ferroelectrics with the first-order phase transition, i.e., with a triple-well potential (See Fig. 1). For this system, when the particle (polar ion) jumps from the middle well to the sideward wells, a paraelectrics-to-ferroelectrics phase transition takes place. Since optimal noise can enhance the hopping of particle between wells, a random-field-induced ferroelectric transition and nonmonotonic behaviors might be observed.

A microscopic Hamiltonian describing order-disorder ferroelectrics is introduced as⁹:

$$H = \begin{bmatrix} -Ep_0 & \frac{\Omega}{2} & 0 & 0 & 0 & 0 & 0 & 0 \\ \frac{\Omega}{2} & Ep_0 & 0 & 0 & 0 & 0 & 0 & 0 \\ 0 & 0 & -\frac{1}{3}Ep_0 & \frac{\Omega}{2} & 0 & 0 & 0 & 0 \\ 0 & 0 & \frac{\Omega}{2} & \frac{1}{3}Ep_0 & 0 & 0 & 0 & 0 \\ 0 & 0 & 0 & 0 & -\frac{1}{3}Ep_0 & \frac{\Omega}{2} & 0 & 0 \\ 0 & 0 & 0 & 0 & \frac{\Omega}{2} & \frac{1}{3}Ep_0 & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 & 0 & -\frac{1}{3}Ep_0 & \frac{\Omega}{2} \\ 0 & 0 & 0 & 0 & 0 & 0 & \frac{\Omega}{2} & \frac{1}{3}Ep_0 \end{bmatrix}, \quad (1)$$

where E is the equivalent field, and p_0 is the dipole moment of the ion in a local polar position. Ω is the tunneling frequency between wells. Under a mean field approximation,

$$Ep_0 = J \frac{\langle p \rangle}{p_0} + E_{\text{ext}}p_0 + E_{\text{rand}}p_0, \quad (2)$$

where $\langle p \rangle$ is the thermal average of the dipole moment, and J is the coupling energy between polar ions. E_{ext} is the applied external electric field, and E_{rand} is the internal random field in the system which is assumed to have a Gaussian distribution with a width σ_e . Hamiltonian in Eq. (1) produces a second-order phase transition for $\Omega < 0.56J$ and a first-order one for $0.56J < \Omega < 2J$ when there is no random field.⁹

From Eq. (2) one can see that the uniform variable E_{ext} is the input signal, and the inhomogeneous E_{rand} is the input random noise. The average polarization $\langle p \rangle$ is the output signal, and appears in the right hand of Eq. (2) as the feedback input through the ferroelectric interaction between polar ions. When there is no external input ($E_{\text{ext}} = 0$), the feedback mechanism can preserve a nonzero output at low temperatures and the system stays in a ferroelectric state. The over-cooled temperature T_- is used to measure the spontaneous phase transition in a cooling process. In Fig. 2, T_- is given as function of the intensity of noise (σ_e) when $\Omega = 0.63J$. It can be seen that T_- increases first and then declines with increasing random field, which is consistent with previous calculation.⁹ T_- reaches its maximum at $\sigma_e = 0.23J/p_0$. This means that a nonzero random field can induce the spontaneous

appearance of the ferroelectric state, i.e., enhance the output signal. Stochastic resonance really exists in the ferroelectrics.

When the temperature is higher than the maximum over-cooled temperature, the system stays in a paraelectric state for any noise. The effect of random fields can then be understood by investigating the response of the system to a weak external field. The ratio of the output and input signals is measured by the dielectric susceptibility,

$$\chi = \frac{P}{\varepsilon_0 E_{ext}} = \frac{N_0 \langle p \rangle}{\varepsilon_0 E_{ext}}, \quad (3)$$

where P is the polarization, and N_0 is the number of polar ions in unit volume. The calculation result is depicted in Fig. 3. It shows that appropriate noise can *greatly enhances* the output signal and results in a peak of the susceptibility, which is just the characteristic signature of stochastic resonance.

In the paraelectric state with no external field, the polarization does not keep zero but fluctuates due to the thermal movement. The polarization fluctuation can be described in terms of the ferroelectric soft mode and the phonon. The dependence of the soft-mode frequency and the phonon occupancy on the random fields is demonstrated in Fig. 4. Nonmonotonic behaviors are observed for both quantities. Stochastic resonance causes the decrease of the soft-mode frequency and the increase of the phonon occupancy, i.e., makes it easier for the thermal fluctuation of polarization to take place.

For ferroelectrics, the random fields are mainly determined by the impurity and the microstructure inhomogeneity in the system. If there are more charge impurities or the microstructure is more inhomogeneous, the random fields are stronger. The features of inhomogeneity include grain size, porosity, grain boundary, chemical inhomogeneity, and domain/twin structure, etc. The inhomogeneity can be controlled by thermal treatments in some degrees. So the stochastic resonance can be realized through the doping and thermal treating. Further experiments in this aspect are needed to testify the theory.

In summary, we have demonstrated a specific stochastic resonance in ferroelectric systems, which is not produced by the temporal noise, but by the spatial noise (random elec-

tric fields). The characteristics of stochastic resonance are revealed via the calculations of the over-cooled temperature, the dielectric susceptibility, the soft-mode frequency, and the phonon occupancy, which all show nonmonotonic dependence on the noise. The spatial stochastic resonance may be useful in materials applications as well as in theoretical interests. For example, the stability of paraelectric and ferroelectric phases can be adjusted by modulating the over-cooled temperature, and the dielectric susceptibility of materials can be increased by selecting appropriate amount of random fields. The mechanics of the spatial stochastic resonance revealed in this paper might also be applicable in a number of inhomogeneous systems whose properties are not well understood.

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FIGURES

FIG. 1. Schematic graphics of a treble-well potential and the hopping of a particle.

FIG. 2. Over-cooled temperature (in unit of J/k_B) of the ferroelectrics described by the Hamiltonian in Eq. (1) as a function of the random field width (in units of J/p_0) when $\Omega = 0.63J$.

FIG. 3. Dielectric susceptibility χ as a function of the random field width (in units of J/p_0) when $\Omega = 0.63J$ and $k_B T = 0.2J$. χ is normalized by a factor $N_0 p_0^2 / \varepsilon_0 J$.

FIG. 4. Random field width dependence of the ferroelectric phonon occupancy when $\Omega = 0.63J$ and $k_B T = 0.2J$. Inserted graphics is the soft-mode frequency.







